Fano Resonance and Orbital Filtering in Multiply Connected Carbon Nanotubes

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Abstract

We investigate the electron transport in multiply connected metallic carbon nanotubes within the Landauer-Buttiker formalism. Quasibound states coupled to the incident states give rise to energy levels of dierent widths depending on the coupling strength. In particular, donorlike states originating from heptagonal rings are found to give a very narrow level. Interference between broad and narrow levels produces Fano-type resonant backscattering as well as resonant tunneling. O ver a signi cantly wide energy range, alm ost perfect suppression of the conduction of electrons occurs, which may be regarded as litering of particular electrons (-pass liter).

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I. IN TRODUCTION

In the past decade, carbon nanotubes (CNTs) have been studied extensively because of their unconventional properties from both the fundam ental research and application point of view [1]. For the application to nanoscale electronic devices, researchers have fabricated various form s of CNTs to engineer their physical properties. sp²-bonded carbon nanostructures have been found to coalesce by electron beam irradiation at high tem perature and new morphologies such as X - and T-shaped junctions have been produced [2, 3, 4]. These developments o er interesting opportunities to study phase-coherent transport in novel geometries. Thus far, phase-coherent transport has been most actively studied in the sem iconductor heterostructures by employing the A haronov-B ohm (AB) interferom eter [5, 6, 7, 8, 9] with an embedded quantum dot in one arm. The measured phase in the open geom etry (as in double-slit experiments) is featured with a sm ooth increase at the resonant tunneling and an abrupt jump by 180 at transmission zeroes. In the closed or unitary geom etry, the conductance generally exhibits the Fano line shape [10]. The Fano e ect usually arises from the coherent interference between a narrow localized level (quantum dot) and a continuum energy spectrum (the arm without a quantum dot) [11]. The Fano e ect has also been identied in the direct transport through a single quantum dot [12, 13]. The CNT is excellent for observing phase coherence phenom ena and there are som e experim ental signatures of the Fano e ect in the CNTs [14, 15, 16], though the detailed mechanism is not fully understood.

In this paper, we report transport properties of a multiply connected carbon nanotube (M CCN) structure as shown in Fig. 1, where a single tube is branched o into two smaller arm s and then they merge into one [17]. We have studied conductance variation system atically by changing the length of the arm s. Both -bonding and (anti)-bonding electron transport channels show resonant tunneling through discrete energy levels(D ELs) in the - nite arm s. The width of the resonant tunneling peaks in the channel is broad and the transmission probability is fairly uniform as a function of energy. The channel, on the other hand, has more interesting structure of either broad or narrow resonant tunneling as will be shown later. C oherent interference between a very broad level (extending over to nearby levels) and its narrow neighboring level is evident in the asymmetric Fano-type line shapes of the transport channel and the corresponding transmission probability is fear-

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tured with both zero and unity. In particular, we nd a nearly perfect suppression of the transmission in a certain nite range of energy. This mechanism can be regarded as electron

Itering of a particular wave function character (-pass Iter), and such a nonequilibrium distribution m ay be maintained over the relaxation length of the electron phase beyond the arm region.

II. COMPUTATIONALDETAILS

O urm odel system, the M CCN, com prises two leads of sem i-in nitem etallic (10,10) CNTs and two arm sof nite (5,5) tubes (e ectively a resistive region) of the same length in between. This structure may be thought as two Y-junctions faced to each other, possibly produced experimentally by electron irradiation on nanotubes. Six heptagons are contained in each of two junction regions where the (10,10) tube and two (5,5) tubes are joined. The length of the arm region is represented by the number (L) of periodic units of the arm chair CNT as shown in Fig. 1. This structure possesses the mirror symmetry with respect to three planes. Two symmetry planes $_{\rm p}$ and $_{\rm c}$, which are, respectively, perpendicular to and containing the (10,10) tube axis, are indicated in Fig. 1. The third one is the plane of the gure containing the tube axis (not indicated in Fig. 1). The electronic structure is described by the single -electron tight-binding H am iltonian

$$H = V_{pp} \qquad \begin{array}{c} X \\ a_{i}^{y}a_{j} + hc: ; \\ a_{ij} > \end{array}$$
(1)

where $\langle i; j \rangle$ denote the nearest neighbor pairs, the hopping integral $V_{pp} = 2:66 \text{ eV}$ [18] and the on-site energy is set to zero.

It is well known that the and bands are crossing at the Ferm i level (E_F) in the arm chair CNTs as shown in Fig. 2. A -bonding state consists of p_z orbitals having the same phase all across the circum ference of the tube. In a -antibonding () state, on the other hand, the constituent p_z orbitals have alternating signs (180 out of phase) along the circum ference of the tube. and states are usually admixed when defects are introduced into the perfectly periodic nanotubes. However, and transport channels rem ain unmixed in our MCCN because of the $_c$ symmetry of the structure. Only if and

states are unmixed, the e ect of interference among dierent levels becomes pronounced and dramatic (e.g., complete suppression of transmission of a level) as described below. Furtherm ore, because two arms are of the same length, we can focus on other e ects than the traditional AB interference due to the path length di erence. In our scattering-state approach, we solve the Schrödinger equation for the whole system by matching the solutions of the tight-binding Ham iltonian in the arm region with that of the lead region at each interface. For given incoming electron waves from the left lead as initial conditions, we obtain the transmitted electrons emerging on the right lead. Conductance is obtained from the Landauer-Buttiker form ula, $G(E) = G_0 Tr(t^yt)$, where G_0 is the conductance quantum (= $2e^2=h$) and t is the transmission matrix [19]. We do not include here extra contact resistance that may arise between external metallic leads and the MCCN.

III. RESULTS AND DISCUSSION

The conductance as a function of the incident electron energy is displayed in Fig. 3 for the cases of L = 5, 9 and 12. To exam ine the structure of the conductance in detail, total conductance is decomposed into two nonmixing contributions of and channels, $G = G_0 (T + T)$, where T and T are the transmission probabilities of the two. We nd the following features common to various L's. (i) T has peaks of magnitude one always and varies very slow ly as a function of energy. (ii) T has both broad and narrow peaks of magnitude one always, and the line shape is highly asymmetric, especially for narrow peaks. (iii) T has no zeroes within the interested energy window while T is featured with zeroes near the narrow asymmetric peaks.

Since the wave function of a state does not have phase variation in the circum ferential direction (i.e., the same sign over the cross-section of the tube) irrespective of n in (n,n) tubes, the wave function in the lead part ((10,10) tube) has alm ost perfect m atch with that in the arm s (two (5,5) tubes), and the transm ission is close to unity in a wide range of energy. In contrast, the conduction of electrons is more complicated because the wave function in the lead part cannot m atch that of the two-arm s region due to the phase variation along the circum ferential direction as mentioned before. The conducting behavior m ay be explained by a close examination of the resonant tunneling through the DELswhich are accommodated in the arm s of (5,5) tubes. Each junction area acts as an elective scattering center for electrons. Thus the MCCN structure m ay be regarded as a double-wall quantum well and we expect the energy quantization by con nement to a nite region of the arm s. With

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increasing length L of (5,5) tubes, the spacing between peaks becomes smaller. Peaks for the states in Fig. 3 show this trend unambiguously. (electrons also experience resonant tunneling via DELs as exemplied in the series of peaks of magnitude unity. However, their line width is so broad that the variation in the conductance is small and uninteresting.) The spectrum of DELs can be roughly estimated from the linear dispersion [20] near E_F for the ideal arm chair nanotube,

$$f_{E}(k)j = \frac{a^{p}\overline{3}}{2}j_{pp}jk \quad k_{F}j; \qquad (2)$$

where a (= 2.46 A) is the lattice constant and k_F (= 2 =3a) is the Ferm i wave vector. Approximate values of the spectrum of DELs are found from the quantization condition kd = m, where d is the elective length of the arm and m is positive integer. For instance, if we took d = La (L = 13) for k = m =d, the DELs near E_F would be 0.93, 0.37, 0.19, and 0.74 eV. A better thing to the exact numerical calculation in Fig. 4 (a) could be obtained if we assumed a longer elective length d (L + 1.5)a, in which case we would have 0.82, 0.32, 0.18, and 0.68 eV. This result is reasonable since the electrons localized in the central ring region are somewhat spread out beyond the arm s as seen, for instance, in the last picture of Fig. 4 (b). This sim ple m odel based on the linear dispersion, of course, has a limitation of obtaining, incorrectly, the same energy separations only.

Coupling to the left and right leads results in the nite lifetime (line broadening) of the DELs. To understand the variation of the line width from peak to peak, we further investigate the structure of the wave functions at the resonant peaks. Besides the linear and

bands crossing at E_F , there exist a conduction band at 0.8 eV and above, and a valence band at 0.8 eV and below in the (10,10) tube. Because of the presence of the heptagonal carbon rings at the junction, donorlike states tend to be produced according to well-known Huckel's (4n + 2) rule for stability [21]. The cycloheptatrienyl cation is a molecular example of the heptagonal ring following Huckel's rule for n = 1. The localized in purity (donor) state is most pronounced if the energy level is close to (and below) aforem entioned conduction band minimum at 0.8 eV. Such localized donorlike states have in fact been found in other defects (nitrogen in purity and Stone-W ales defect) of the nanotube as well [22, 23]. The peak C in Fig. 4 (or sharp peaks closest to 0.8 eV in Fig. 3) corresponds to this state and has a narrow line shape owing to the relatively well-localized (long lifetim e) character of such an origin. The DELs further away from the conduction band minimum are less localized and thus broader.

We also compare the wave functions around the peaks and the nodes of the conductance curve. The wave functions at peaks of T have large amplitude in two arms so that incident electrons are in resonance with the states in the region. In contrast, the wave functions of the band at the U-shaped valley (e.g., at 0.46 eV in Fig. 4 (b)) are depleted inside two arms, which means an electric disconnection of two leads and the suppression of the electron conduction. Unlike in the electron case, the phase variation across the cross-section of the tube is very rapid in the state and it is very dil cult to match the wave function at the junction boundary for a general value of energy, hence substantial reduction in conductance.

So far, we have accounted for the interesting phenom enon of line width variations from level to level. Such a variation leads to even more profound consequences on the structure of the transmission probability as we shall describe below. In the 1D mesoscopic systems such as the double-barrier quantum wells, if all the DELs are coupled to the continuum of lead states with alm ost the same coupling strength and the relative signs of couplings to two leads are alternating from level to level, the transmission zero does not occur [24, 25]. However, when one energy level is coupled by farm ore strongly to the leads and acts like a broad band interfering with other narrow levels, the transm ission zero may take place [25]. Our system falls in the latter case. As the energy of the DELs is increased, the number of nodes along the two arms increases one by one and in turn the relative signs of the wave functions at two junctions are oscillating for DELs. The DELs in the arm region are coupled to the left and right (10,10) tube leads with the same coupling strength but with variable signs. The signs of the coupling constants at both junctions are determined by the parity of the wave functions with respect to the rejection symmetry plane, p. For an even-parity state, the signs of coupling constants at two junctions are the same, but they are opposite for an odd-parity state. This alternating parity under $_{p}$ symmetry operation is clearly visible in Fig. 4 (b) for DELs at 0.32 (even), 0.18 (odd), and 0.59 eV (even). In the presence of the p symmetry (plus the time-reversal symmetry which obviously exists in the absence of applied magnetic elds), it is well known that the perfect transmission (T = 1) is allowed to occur at all resonant peaks in the system [26]. On the other hand, the transmission zero is generally not allowed in the energy range between one level and its nearest neighbor level interfering each other [25]. It is only when a broad level extends beyond the nearest neighbor narrow level that a transm ission zero occurs at the energy between its nearest and

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next nearest neighbor narrow level.

To con m this argument, we t the curve of T for L = 13 with the multilevel generalization of the G reen's function formula [27, 28, 29]. The expression for T contains, as param eters, D E Ls (E_i) and coupling constants to right (V_{Ri}) and left leads (V_{Li}) [25, 27, 28, 29].

$$T (") = 4Trf _{L}D^{r} (") _{R}D^{a} (")g;$$
 (3)

$$D^{r;a}(") = ["I E i]^{1};$$
 (4)

where L_{R} is the coupling matrix between the resistive and lead region on the left or right, D^{r;a} is the retarded or advanced G reen's function, $E_{ij} = E_{i ij}$, $i_{ij} = L_{ij} + R_{ij} =$ $N_L V_{iL} V_{Lj} + N_R V_{iR} V_{Rj}$ and N_{LR} is the density of states in the lead on the left or right (N $_{\rm L}$ = N $_{\rm R}\,$ in the present case). We use seven DELs and their diagonal components of $\,$. Values of DELs (ii) in eV are as follows: 1.330(0.139), 0.859(0.194), 0.300(0.132), 0.178 (0.025), 0.584 (0.013), 1.100 (0.183), and 1.700 (0.250). The conductance curve in much wider energy range than the one presented in Fig. 4 has been tted for more complete results. As m entioned above, relative signs of the wave function at two junctions alternate from one level to the next so that we set $V_{Ri} = V_{Li}$, where is 1 (1) for the even (odd) parity state with respect to p. represents the broadening of a particular level and results in the nite energy width of the conductance peak. In Fig. 4, A, B, and C are the broadened peaks associated with respective DELs. At a given energy, contributions from tails of two or more broadened peaks overlap and give rise to an asymmetric line shape. For instance, between A and B (i.e., the right-hand side of A and left-hand side of B), conduction paths interfere constructively and no transmission zero occurs. However, on the right-hand side of B, A and B interfere destructively (since the energy is greater than both A and B) and produce a transmission zero. Since peak C is very narrow, its constructive interference on B (in the energy range between B and C) is much less than the destructive interference from A and unable to change the result. In fact, there are two transm ission zeroes between B and C, one nearer to B which is obtained as above and the other nearer to C which is obtained by the destructive interference between C and the next broad peak above C (not shown). Here we emphasize that the transmission zeroes result from the interference between the abstract conduction paths through the energy levels in the Hilbert space. The curve tting with Eq.(3) is practically indistinguishable from the -channel conductance of our M CCN, indicating that the simple m odel with the multilevel transm ission formula is valid for explaining the Fano resonance structures and the transm ission zeroes. We also observe that, in a certain nite energy range, the conductance of electrons is almost zero while that of electrons is not reduced appreciably. For instance, the transm itted electrons of character for L = 5 in Fig. 3(a) constitute less than 8% of the total transm itted electrons in the energy range between 0 and 0.5 eV. This may be regarded as orbital ltering of a particular wave function character (-pass lter). This result can be used for a further fundam ental research on the orbital character in nanostructures or an application to current switching in nanotubes.

IV. SUMMARY

We have carried out tight-binding calculations of conductance of multiply connected metallic CNTs with the mirror symmetry. The channel is well-conducting and has very broad resonance peaks. The channel exhibits Fano resonance structures. The Fano e ect originates from the interference between broad and narrow electronic levels in the arm region. It is shown that the present system transmits predominantly over electrons in a certain energy range.

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[Figure Captions]

Figure 1: M odel of M CCN with L=10. $_{p}$ and $_{c}$ denote the planes of m intersymmetry. Figure 2: B and structure of the (10,10) arm chair carbon nanotube near the Ferm i level, $E_{F} (= 0)$.

Figure 3: (color). Conductance as a function of the incident energy E for the MCCNs. The Ferm i level is set to zero. (a) L=5, (b) L=9, and (c) L=12.

Figure 4: (color). Conductance and wavefunctions for L=13. In (a), the full numerical calculation for (solid red line) is indistinguishable from the twith the multiple Fano resonance formula (dashed red line). In (b), the red and blue colors indicate signs and the size of the spheres is the amplitude of the wavefunction.

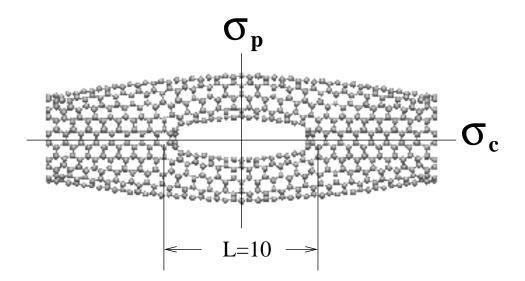
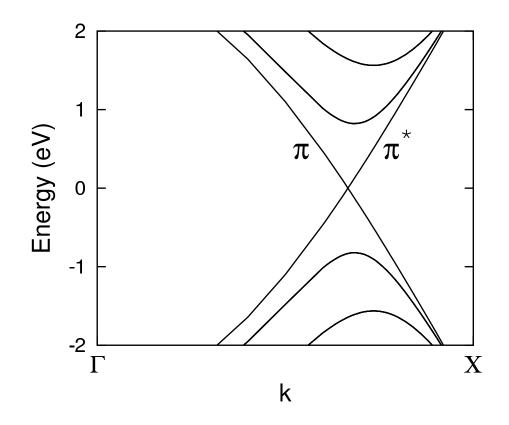


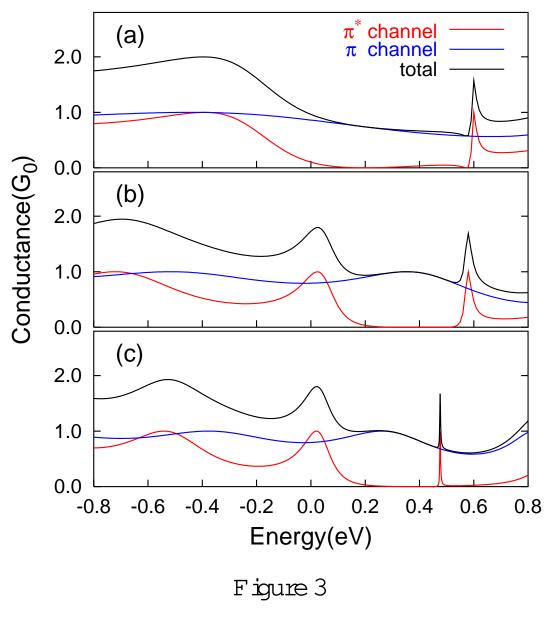
Figure 1

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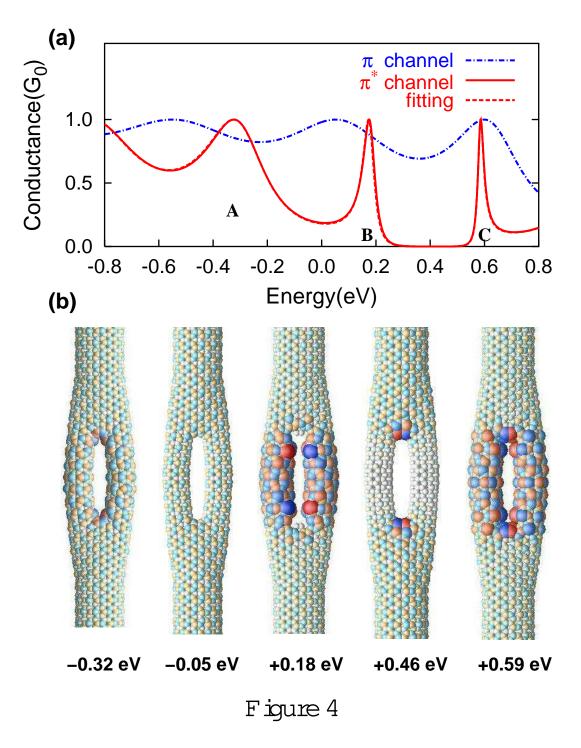




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